

The Mesoscopic Kondo Box: A Mean-Field Approach

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We study the mesoscopic Kondo box, consisting of a quantum spin 1/2 interacting with a chaotic electronic bath as can be realized by a magnetic impurity coupled to electrons on a quantum dot, using a mean-field approach for the Kondo interaction. Its numerical efficiency allows us to analyze the Kondo temperature, the local magnetic susceptibility, and the conductance statistics for a large number of samples with energy levels obtained by random matrix theory. We see pronounced parity effects in the average values and in the probability distributions, depending on an even and odd electronic occupation of the quantum dot, respectively. These parity effects are directly accessible in experiments.

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I. INTRODUCTION

Many-body effects have been a key interest in condensed matter physics for many decades. A prime example is the Kondo effect¹ that, in its original context, refers to an increase of the resistance with decreasing temperature below the characteristic Kondo temperature T_K in metals containing magnetic impurities. The significant progress in the fabrication of mesoscopic and nanoscopic systems has lead to many alternative realizations of Kondo systems.²⁻⁵ A nice example is the so-called Kondo box,⁶ where a finite number of electrons, confined in a quantum dot, is coupled to a single magnetic impurity. Their discrete energy spectrum introduces the mean level spacing Δ as new energy scale. It has been shown that physical quantities strongly deviate from the metallic behavior for $\Delta \gtrsim T_K$, i.e., when the size of the Kondo cloud screening the impurity would become larger than the size of the system.⁶⁻¹⁰ For example, they show parity effects, i.e., characteristic differences for an even and odd number of electrons in the system.¹¹⁻¹³ Kondo physics in the presence of a chaotic dot geometry and disorder, respectively, has been studied within the Kondo disorder model (KDM)¹⁴⁻¹⁶ using Anderson's poor man's scaling approach¹⁷ to calculate the Kondo temperature. However, poor man's scaling cannot describe the strong coupling phase below T_K , and non-perturbative methods are needed, for example quantum Monte Carlo simulations (QMC),¹⁸ numerical renormalization group^{19,20} or the non-crossing approximation.²¹ These methods are either numerically expensive or not reliable for low temperatures $T \ll T_K$.²² The QMC has been used by Kaul *et al.*²³ to calculate the local magnetic susceptibility χ_0 for three different realizations of a chaotic system showing that mesoscopic fluctuations lead to significant deviations from bulk universality. However, parity effects and systematic studies of mesoscopic fluctuations were neither considered here nor in the KDM studies.

In the present Letter we use a mean-field approach which had been developed initially for the single impurity Kondo model in a macroscopic metal,²⁴ and later adapted to some particular mesoscopic Kondo systems.^{8,25} We first introduce the method in the framework of the chaotic Kondo box model.

We then discuss the resulting probability distributions of T_K , χ_0 , and the conductance G . Their knowledge and the characteristic differences between even and odd electronic fillings make the comparison with experiments a realistic endeavor for the near future.

II. MODEL

We investigate the Kondo box model:⁶ An electronic bath, e.g. quantum dot, with discrete energy levels ε_l , coupled to a local spin $\mathbf{S} = 1/2$. The system is described by the Kondo Hamiltonian,¹

$$H = \sum_{l\sigma} (\varepsilon_l - \mu) d_{l\sigma}^\dagger d_{l\sigma} + J_K \mathbf{S} \cdot \mathbf{s}_0. \quad (1)$$

Operator $d_{l\sigma}^\dagger$ ($d_{l\sigma}$) creates (annihilates) a dot electron with level index $l = 1, \dots, N$ and spin component $\sigma = \uparrow, \downarrow$. The chemical potential μ , related to an external gate voltage, fixes the number of dot electrons N_C , which effectively accounts for Coulomb blockade. In addition, the case of a fixed $\mu = 0$ rather than a fixed N_C will be considered. The local spin density $\mathbf{s}_0$ of the dot electrons at the impurity position is given by

$$s_0^z = (d_{0\uparrow}^\dagger d_{0\uparrow} - d_{0\downarrow}^\dagger d_{0\downarrow}) / 2, \quad (2)$$

$$s_0^+ = d_{0\uparrow}^\dagger d_{0\downarrow}, \quad (3)$$

$$s_0^- = d_{0\downarrow}^\dagger d_{0\uparrow}, \quad (4)$$

where the local electron operator $d_{0\sigma}$ is related to the dot electron operators by

$$d_{0\sigma} = \sum_l A_l^* d_{l\sigma}. \quad (5)$$

The complex coefficients A_l correspond to the non-interacting wave function amplitude of level ε_l at the impurity site ($\sum_l |A_l|^2 = 1$) and are assumed to be spin-independent. The quantum dot is thus characterized by N energy levels

ε_l , distributed from $-W/2$ to $W/2$, and the corresponding amplitudes A_l . In this Letter, our focus will be on chaotic quantum dots where the ε_l are realized within random matrix theory²⁶ to be a Gaussian orthogonal ensemble unfolded to a constant density of states, and the intensities $|A_l|^2$, obtained within the random wave model,²⁷ are Porter-Thomas distributed. For reasons of comparison we also introduce a system with equidistant ε_l and constant A_l that we will refer to as the clean system, cf., e.g., Fig. 1.

III. MEAN-FIELD APPROXIMATION

For each given configuration, we treat the Kondo interaction in a mean-field approximation.²⁴ The magnetic impurity spin is thus described in terms of fermionic operators $f_{\uparrow,\downarrow}$ obeying the constraint $f_{\uparrow}^\dagger f_{\uparrow} + f_{\downarrow}^\dagger f_{\downarrow} = 1$. The Kondo interaction in (1) then reads

$$J_K \mathbf{S} \cdot \mathbf{s}_0 = \frac{J_K}{2} \sum_{\sigma\sigma'} f_{\sigma}^\dagger f_{\sigma'} d_{0\sigma'}^\dagger d_{0\sigma} - \frac{J_K}{4} \sum_{\sigma} d_{0\sigma}^\dagger d_{0\sigma}. \quad (6)$$

The first term describes the spin flip processes, while the second term corresponds to a local potential scattering and is not further considered in the following. The mean-field treatment of the Kondo box Hamiltonian invokes two approximations, (i) replacing the quartic spin flip term by a quadratic term, $r \sum_{\sigma} (f_{\sigma}^\dagger d_{0\sigma} + \text{h.c.})$, where the effective hybridization r is determined self-consistently by minimizing the free energy, and (ii) introducing a static Lagrange multiplier λ , in order to fulfill (on average) the constraint of a single impurity spin. So the Hamiltonian (1) of the Kondo box in mean-field approximation reads $H = H_{\uparrow} + H_{\downarrow}$, with

$$H_{\sigma} = \sum_l \left[(\varepsilon_l - \mu) d_{l\sigma}^\dagger d_{l\sigma} + r (A_l^* f_{\sigma}^\dagger d_{l\sigma} + \text{h.c.}) \right] - \lambda f_{\sigma}^\dagger f_{\sigma}. \quad (7)$$

Hereafter, since the mean-field approximation decouples the spin components, we suppress the spin index. The mean-field parameter r , the Lagrange multiplier λ , and the chemical potential μ , satisfy the self-consistency equations

$$-\frac{r}{J_K} = \langle f^\dagger d_0 \rangle = T \sum_l A_l^* \sum_{i\omega_n} G_{\text{lf}}(i\omega_n), \quad (8)$$

$$\frac{1}{2} = \langle f^\dagger f \rangle = T \sum_{i\omega_n} G_{\text{ff}}(i\omega_n), \quad (9)$$

$$\frac{N_C}{2} = \sum_l \langle d_l^\dagger d_l \rangle = T \sum_l \sum_{i\omega_n} G_{\text{ll}}(i\omega_n), \quad (10)$$

with the temperature T and the fermionic Matsubara frequencies $\omega_n = (2n+1)\pi T$. Here, the thermal average $\langle \dots \rangle$ is expressed in terms of one-particle Green's functions, which are calculated from the mean-field Hamiltonian (7) using

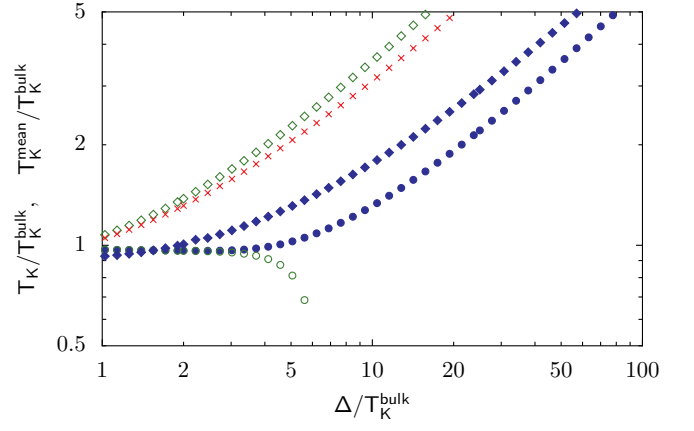


FIG. 1: (Color online) Kondo temperature T_K , for the clean system (N_C even $\circ$, N_C odd $\bullet$) and average Kondo temperature T_K^{mean} , for the chaotic system (N_C even $\diamond$, N_C odd $\blacklozenge$, $\mu = 0$ $\times$), as functions of Δ/T_K^{bulk} .

equations of motion. We find

$$G_{\text{ff}}(i\omega_n) = \left[i\omega_n + \lambda - |r|^2 \sum_l \frac{|A_l|^2}{i\omega_n + \mu - \varepsilon_l} \right]^{-1}, \quad (11)$$

$$G_{\text{lf}}(i\omega_n) = \frac{r A_l}{i\omega_n + \mu - \varepsilon_l} G_{\text{ff}}(i\omega_n), \quad (12)$$

$$G_{\text{ll}}(i\omega_n) = \frac{1}{i\omega_n + \mu - \varepsilon_l} \left[1 + \frac{|r|^2 |A_l|^2}{i\omega_n + \mu - \varepsilon_l} G_{\text{ff}}(i\omega_n) \right]. \quad (13)$$

IV. RESULTS

We now present the results starting with a discussion of T_K , followed by an analysis of χ_0 and G . In contrast to previous studies of chaotic Kondo systems²³ we are able to distinguish between an even and odd number N_C of dot electrons, cf. Eq. (10). We find pronounced parity effects in the probability distributions of T_K , χ_0 and G . Solving only Eqs. (8) and (9), we can furthermore address the case of a non-fixed N_C , which corresponds to fixing $\mu = 0$ as done by Kaul *et al.*²³ All the numerical results presented here are obtained for $N = 100$ levels, and an electronic filling $N_C = 101$ and 102 in the odd and even cases, respectively. We checked that N is large enough for band edge effects to not play a role.

A. Kondo temperature

Within the mean-field approximation, the Kondo temperature T_K characterizes a transition between a high temperature phase, where the effective hybridization r , vanishes, and a low temperature phase with $r \neq 0$. More accurate methods would rather describe a crossover, around T_K , between weakly and strongly coupled regimes. Despite the oversimplified description of the $T > T_K$ weakly coupled regime,

the mean-field approximation provides a good estimation for T_K , and a good description of the physical properties in the $T < T_K$ strongly coupled regime.¹ Using Eqs. (8, 11, 12), we find the well known Nagaoka-Suhl equation²⁸ for T_K

$$\frac{2}{J_K} = \sum_l \frac{|A_l|^2}{\varepsilon_l - \mu} \tanh\left(\frac{\varepsilon_l - \mu}{2T_K}\right). \quad (14)$$

In the bulk limit $\Delta/W \rightarrow 0$, one obtains the relation¹

$$T_K^{\text{bulk}} \approx 1.13 \sqrt{W^2/4 - \mu^2} \exp(-W/J_K). \quad (15)$$

In the following, we use T_K^{bulk} , rather than J_K , as the reference energy scale characterizing the Kondo coupling.

The Kondo temperature probability distribution, $p(T_K)$, is studied by solving Eq. (14) for various realizations. The result is mostly a regular, smooth function, which is depicted in the main part of Fig. 2. In addition to the data shown, there is a non-vanishing contribution $p(T_K = 0)$ for N_C even that is analyzed in the inset of Fig. 2. Note that T_K^{mean} is the average Kondo temperature computed from the regular part of $p(T_K)$ only.

Figure 1 shows T_K^{mean} for a chaotic system as a function of Δ/T_K^{bulk} , compared to the clean system, each for an even and odd electronic filling of the dot. In the bulk limit ($\Delta/T_K^{\text{bulk}} \rightarrow 0$), the Kondo temperatures for even and odd N_C coincide as expected, while there is a pronounced parity effect for increasing Δ/T_K^{bulk} , i.e., smaller systems and/or decreasing Kondo interaction strength. For the clean system, T_K vanishes in the even case at the critical value $\Delta/T_K^{\text{bulk}} \approx 6.28$.¹⁵ In all other cases and for larger values of Δ/T_K^{bulk} , the (average) Kondo temperature scales with the level spacing Δ , which becomes, in this limit, the only energy scale of the problem.

The inset of Fig. 2 shows the fraction P_0 of unscreened impurities at $T = 0$ as a function of Δ/T_K^{bulk} . We find that it is always possible to form the Kondo singlet in the odd case (no unscreened impurities), since the chemical potential coincides with an energy level. In the even case, the Kondo effect disappears, on average, with increasing mean level spacing Δ , $P_0 \rightarrow 1$.

The parity effects visible in T_K^{mean} are even more dramatic in the probability distribution $p(T_K)$ shown in Fig. 2 for $\Delta/T_K^{\text{bulk}} = 2$ and 100. Whereas for $\Delta/T_K^{\text{bulk}} = 2$ the average Kondo temperatures are almost the same, there is already a significant difference in $p(T_K)$. Most remarkable is a power law scaling, $p(T_K) \propto T_K^{-\nu}$, over several orders of magnitude in the odd case. Its existence was pointed out previously¹⁴⁻¹⁶ for a related system, the Kondo disorder model (KDM). The KDM describes a Kondo impurity in a bulk electronic bath for which disorder can be included continuously. The chaotic Kondo box that we consider here can in many respects be considered as a KDM with a non-tunable, i.e., fixed, disorder strength. Instead, another parameter can be tuned, Δ/T_K^{bulk} , allowing for a continuous connection between the bulk, $\Delta/W = 0$, and the mesoscopic, $\Delta \sim T_K^{\text{bulk}}$ regimes. Using Eq. (14) we can show analytically that the power law scaling of $p(T_K)$, with the constant exponent $\nu = 1/2$, is a direct consequence of the Porter-Thomas distribution of the

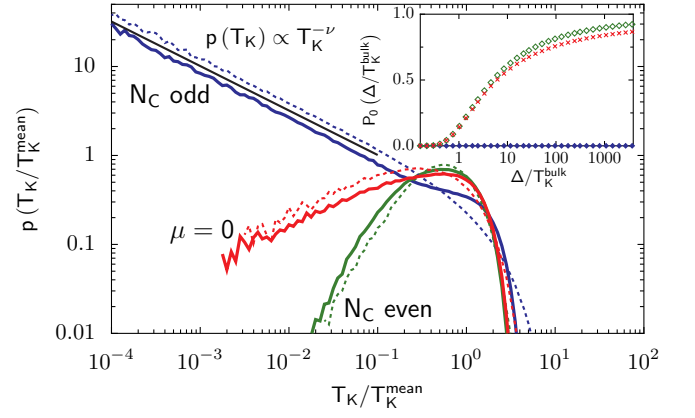


FIG. 2: (Color online) Kondo temperature distribution for a chaotic system with $\Delta/T_K^{\text{bulk}} = 2$ (solid lines), 100 (dashed lines) for fixed N_C and $\mu = 0$. For N_C odd we see a power law $p(T_K) \propto T_K^{-\nu}$, indicated by the straight line. Inset: probability for vanishing T_K in a chaotic system as function of Δ/T_K^{bulk} for N_C even ($\diamond$), N_C odd ($\circ$), and $\mu = 0$ ($\times$).

intensities $|A_l|^2$. It persists for $\Delta \geq T_K^{\text{bulk}}$ and is in agreement with Cornaglia *et al.*¹⁶ In the case of even occupation, a linear probability distribution, $p(T_K) \sim T_K$ was found for small T_K ,¹⁵ which is also consistent with our results. For values $\Delta < T_K^{\text{bulk}}$ the level structure is no longer important, so all the probability distributions are similar to a Gaussian around T_K^{mean} .

B. Magnetic susceptibility

Within the mean-field approximation, the Kondo spin static susceptibility

$$\chi_0(T) \equiv \frac{1}{3} \int_0^{1/T} d\tau \langle \mathbf{S}(\tau) \cdot \mathbf{S}(0) \rangle, \quad (16)$$

reads

$$\chi_0(T) = T \sum_{i\omega_n} G_{\text{ff}}(i\omega_n) G_{\text{ff}}(-i\omega_n). \quad (17)$$

In the decoupled phase, $T > T_K$, we recover a Curie law $\chi_0(T) = 1/4T$, which characterizes a free spin 1/2. In order to describe the screening in the Kondo phase $T < T_K$, we analyse the local effective moment $T \chi_0(T)$, which is equal to 1/4 for a free spin, and vanishes for a fully screened state. Figure 3 (upper panels) shows the local effective moment for fixed N_C as well as for $\mu = 0$ at $\Delta/T_K^{\text{bulk}} = 2$. The clean system (circles) shows parity effects as expected.⁹ In the odd case, the impurity spin is fully screened at $T = 0$, while in the even case it remains unscreened or partially screened for all temperatures. In the chaotic system the average $T \chi_0$ only slightly differs from the clean case, since the screening of the impurity spin is closely related to the number N_C of dot electrons. More information provides the probability distribution $p(T \chi_0)$, showing that in the odd case the impurity is screened

at $T = 0$ for all configurations in the Kondo regime. For N_C even all values between 0 and $1/4$ are taken as $T \rightarrow 0$. This characteristic parity dependence in $p(T\chi_0)$ should be directly accessible in experiments. The $\mu = 0$ case contains both features: an increased probability for a screened impurity and a non-vanishing probability for having an unscreened impurity.

C. Conductance

Here, we consider the chaotic Kondo box connected to two leads, denoted by $\alpha = L, R$. We study the tunneling conductance through the box in the linear response regime. The Hamiltonian of the full system is obtained from the Kondo box Hamiltonian (1) by

$$H \mapsto H + \sum_{k\sigma\alpha} \varepsilon_k c_{k\sigma\alpha}^\dagger c_{k\sigma\alpha} + \sum_{lk\sigma\alpha} \left(t_{lk}^\alpha d_{l\sigma}^\dagger c_{k\sigma\alpha} + \text{h.c.} \right) \quad (18)$$

where the second term describes the c -electrons of the leads and the third term the dot-lead coupling. The leads are assumed to be ideal metals, therefore, the tunneling couplings do not depend on the momentum k , $t_{lk}^\alpha = t_l^\alpha$. In order to mimic the chaotic nature of the Kondo box, we also assume that the tunneling couplings are randomly distributed, with second moments $\langle t_l^\alpha t_{l'}^{\alpha'} \rangle = t^2 \delta_{ll'} \delta_{\alpha\alpha'}$ (here, δ denotes the Kronecker symbol, and t is a characteristic tunneling energy). In the presence of a finite bias voltage between the leads V , the current through the Kondo box is²⁹

$$J(V) = \frac{2e}{h} \int d\omega [f_R(\omega) - f_L(\omega)] \text{Im}[\text{Tr}\{\mathbf{T}\mathbf{G}\}], \quad (19)$$

where $f_{R/L} = f(\omega \pm eV/2)$ is the Fermi function in the leads, and $\mathbf{G}$ is the Green's function matrix of the dot electrons, in the presence of the leads.

$$\Gamma_{ll'}^\alpha \equiv 2\pi \sum_k \rho(\varepsilon_k) t_{lk}^\alpha t_{kl'}^\alpha \quad (20)$$

is the tunneling matrix, where ρ denotes the density of states of the leads. Hereafter, we approximate the tunneling matrix by its average value, $\Gamma_{ll'}^\alpha \approx \gamma \delta_{ll'}$, where $\gamma \sim \rho t^2$. A fully self-consistent mean-field treatment of the system with a finite bias voltage would require to take into account the renormalization of the mean-field parameters, in the presence of the leads, similarly to the approach of Aguado *et al.*²⁵ Here, we consider the linear response regime, $V \rightarrow 0$, as well as the tunneling limit, $\gamma \rightarrow 0$. The mean-field parameters r , λ and μ are thus not modified by the leads. Furthermore, within the mean-field approximation, the effective Kondo box Hamiltonian (7) is non-interacting. Therefore, the Dyson equation for

$\mathbf{G}$ reads

$$\mathbf{G}^{-1} = \mathbf{G}_0^{-1} - i\mathbf{\Gamma}, \quad (21)$$

where the Kondo box (i.e. without the leads) d -electron Green's function $\mathbf{G}_0$ is given by Eq. (13).

The conductance $G = dJ/dV$ is shown in Fig. 3 (lower panels) as a function of T/T_K . There are clear parity effects: for N_C even, the low temperature limit is $G = 1$ (in units of the quantum of conductance $2e^2/h$), no matter what the underlying realization is. However, for an odd occupation number the conductance goes to $G = 0$, since the Kondo singlet blocks the transport channel. The low temperature limit for $\mu = 0$ depends on the distance between the chemical potential μ and the closest energy level.

V. CONCLUSIONS

We have presented a mean-field approach to the mesoscopic Kondo box problem that allows a very efficient computation of all physical quantities of interest – T_K , χ_0 , and G – that are easily, and on an equal footing, accessed via the one-body Green's functions. In contrast to other methods, we are able (i) to reach very low temperatures $T \sim 0.001 T_K$ within reasonable computation time and (ii) to calculate the probability distributions based on a large number (at least 50 000) of realizations of the chaotic Kondo box. Our results agree with those of other approaches when available. Concretely, we find deviations from the bulk system to occur in form of pronounced parity effects. For realizations with an odd number of dot electrons, we confirm and refine the power law distribution of $p(T_K)$. The significant parity effects in the magnetic susceptibility and the conductance provide the basis for a direct comparison with experiments. For example, the expected spread in the experimental values in quantum dots with a certain (even or odd) number of electrons, fixed via Coulomb blockade, will be either large or small, and is therefore already accessible by measuring few samples.

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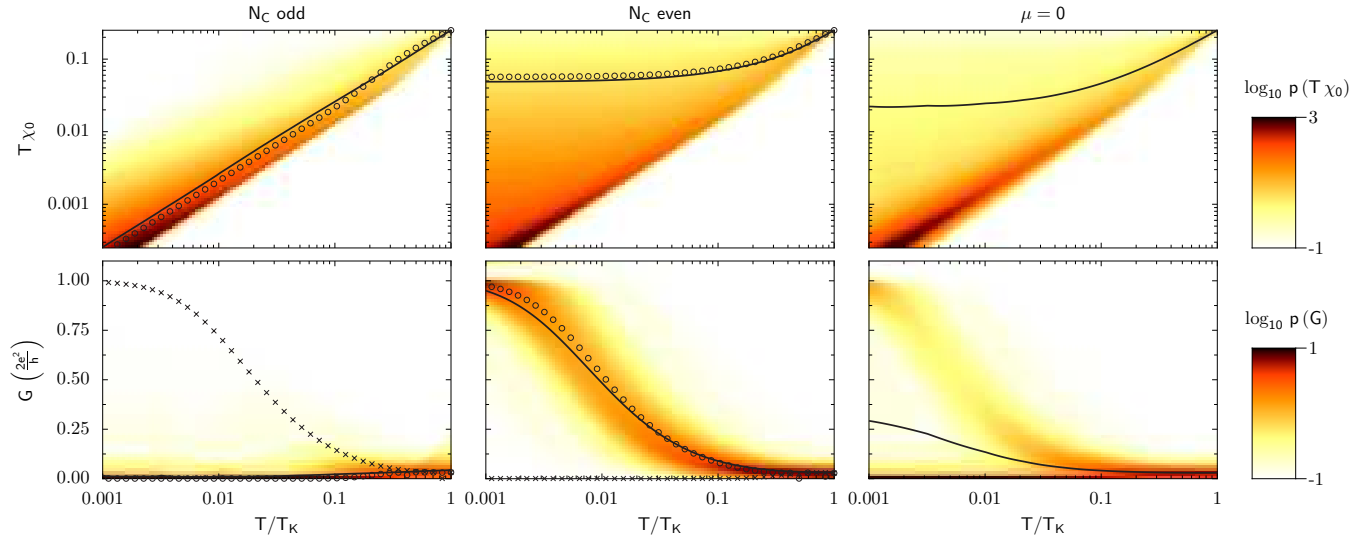


FIG. 3: (Color online) Distributions of the local effective moment $T\chi_0$, (upper panels) and the conductance G , (lower panels) for N_C odd (left), N_C even (center) and $\mu = 0$ (right) as functions of T/T_K . Here, we use $\Delta/T_K^{\text{bulk}} = 2$. The clean system is symbolized by the circles ($\circ$), the solid lines mark the chaotic average values.

Local effective moment: A broad distribution of values in the N_C even case is contrasted with the more confined distribution for N_C odd. This pronounced parity effect is directly related to the formation of the Kondo singlet.

Conductance: The probability distribution of the conductance at zero bias voltage shows clear parity effects. The conductance for the non-interacting case ($J_K = T_K^{\text{bulk}} = 0$) is represented by the stars ($\times$), showing that the parity is switched by one, due to the Kondo impurity effective contribution.

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